TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX125F,TC74LCX125FN,TC74LCX125FT,TC74LCX125FK

Low-Voltage Quad Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX125F/FN/FT/FK is a high-performance CMOS quad bus buffers. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for inputs

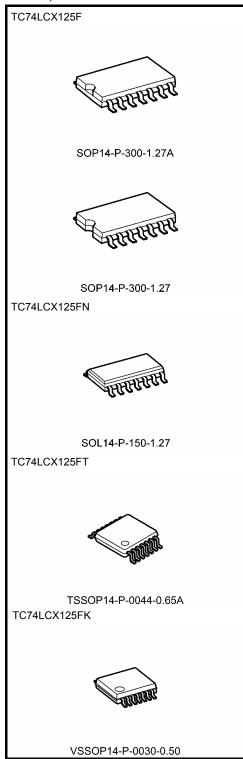
This device requires the 3-state control input \overline{OE} to be set high to place the output into the high impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 125 type

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

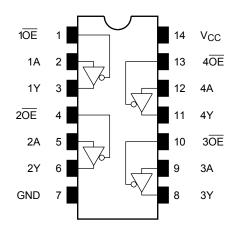
 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

1 OE -	1 _	EN	_	∇	3 1
1A -	2			V	
2 OE -	4 📐				6 04
2A -	5				2Y
3 OE -	10 📐				8 0.4
3A -	9				3Y
4 OE -	13 📐				44
4A -	12				<u>11</u> 4Y
7/1					

Truth Table

Inp	uts	Outputs
ŌĒ	Α	Y
Н	Х	Z
L	L	L
L	Н	Н

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	−0.5 to 7.0	V	
DC input voltage	V _{IN}	−0.5 to 7.0	V	
		-0.5 to 7.0 (Note 2)		
DC output voltage	Vout	$-0.5 \text{ to V}_{CC} + 0.5 $ (Note 3)	V	
Input diode current	I _{IK}	-50	mA	
Output diode current	lok	±50 (Note 4)	mA	
DC output current	lout	±50	mA	
Power dissipation	P _D	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
Tower supply voltage	VCC	1.5 to 3.6 (Note 2)	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 3)	V	
Output voltage	VOU1	0 to V _{CC} (Note 4)	V	
Output current	I _{OH} /I _{OL}	±24 (Note 5)	mA	
Output current	IOH/IOL	±12 (Note 6)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
	1				V _{CC} (V)			
Input voltage	H-level	V _{IH}		_	2.7 to 3.6	2.0		V
pat voltage	L-level	V_{IL}		_	2.7 to 3.6	_	8.0	·
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level	.,		I _{OL} = 12 mA	2.7	_	0.4	
	L-ievei	V _{OL}		I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μА
			$V_{IN} = V_{IH}$ or V_{IL}		0.71.00			
3-state output OFF state current		loz	V _{OUT} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
Power-off leakage current		l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μА
Ouissant suggle suggest		laa	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	10.0	
Quiescent supply of	urrent	Icc	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μΑ
Increase in Icc per	input	Δlcc	C V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6	_	500	



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	6.5	- ns
1 Topagation delay time	t_{pHL}	rigure 1, rigure 2	3.3 ± 0.3	1.5	6.0	
Output enable time	t_{pZL}	Figure 1, Figure 3	2.7		8.0	- ns
Output enable time	tPZH		3.3 ± 0.3	1.5	7.0	
Output dipable time	t_{pLZ}	Figure 1, Figure 3	2.7		7.0	20
Output disable time	t_{pHZ}	Figure 1, Figure 3	3.3 ± 0.3	1.5	6.0	ns
Output to output alcow	t _{osLH}	(Nists)	2.7	_	_	20
Output to output skew	t _{osHL}	(Note)	3.3 ± 0.3		1.0	ns

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

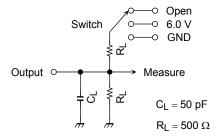
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (No	te) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$

AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{pLZ} , t _{pZL}	6.0 V		
t _{pHZ} , t _{pZH}	GND		

Figure 1

AC Waveform

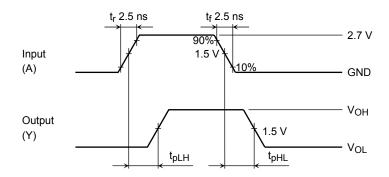


Figure 2 tpLH, tpHL

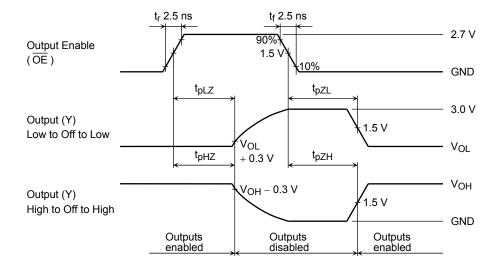
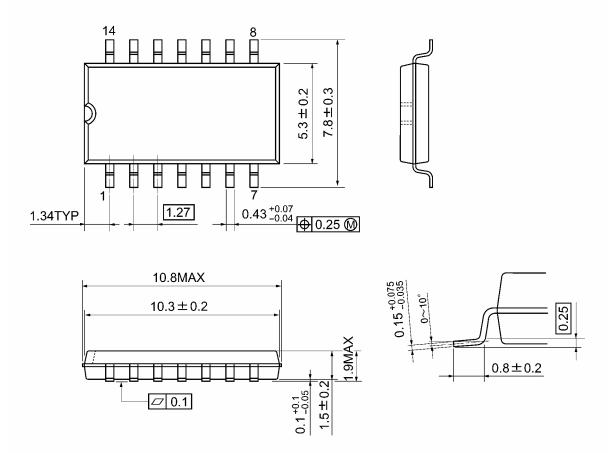
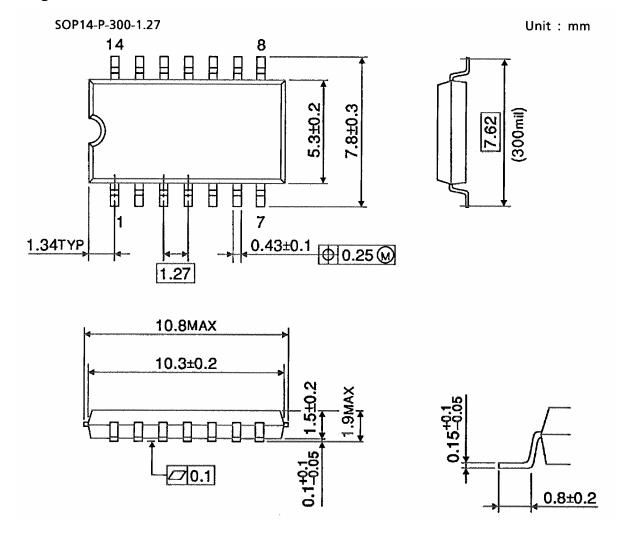


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

SOP14-P-300-1.27A Unit: mm

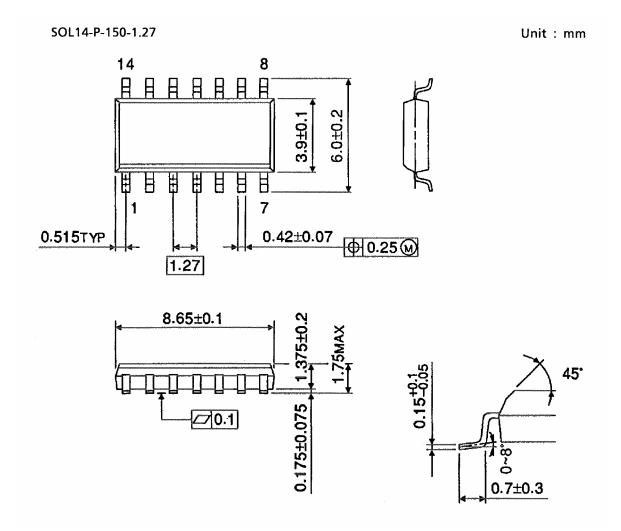


Weight: 0.18 g (typ.)



Weight: 0.18 g (typ.)

Package Dimensions (Note)

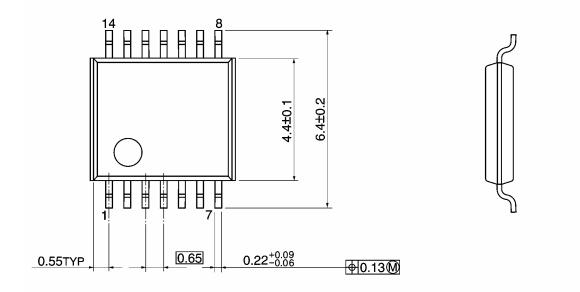


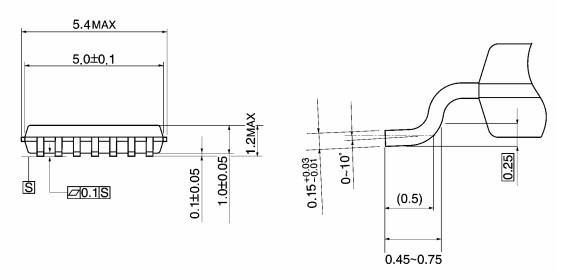
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Note: This package is not available in japan.

Weight: 0.12 g (typ.)

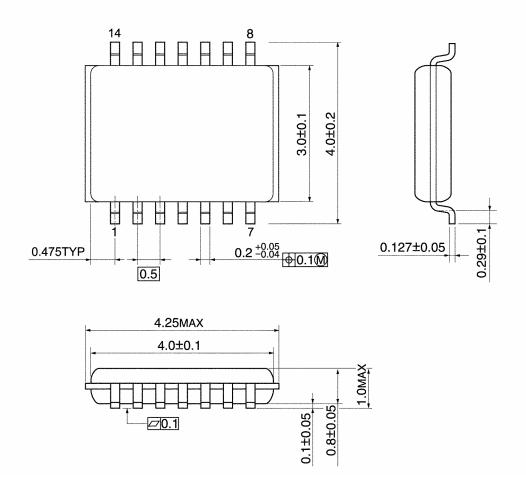
TSSOP14-P-0044-0.65A Unit: mm





Weight: 0.06 g (typ.)

VSSOP14-P-0030-0.50 Unit: mm



10

Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A VSSOP14-P-0030-0.50

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